

General Motivation Potential impact

• Silicon high capacity (3579Ah/kg) can increase the theoretical energy density and specific energy of the cell of 25-30% respect to graphite-based lithium-ion cells

Open issues

- ► Mechanical degradation due to large volumetric expansion (a volumetric strain of about 270%) generate plastic flow and substantial stresses in the material, leading to mechanical failure after a few charge-discharge cycles
- Capacity loss in solid-electrolyte interface formation

Our contribution

• To aid the development of failure tolerant architectures, we develop a continuum model that predicts stress, plastic flow, diffusion and the electrochemical response of a Si anode during lithiation

Test and Calibration

- ► In situ measurements [Sethuraman et al., 2010] from ad hoc experiments are used to calibrate and verify the predictive capability of the model
- Material parameters under investigation
- mechanical properties of Si as functions of Li concentration
- transport properties of Li through Si
- ▶ parameters related to the **solution chemistry** of Li in Si (i.e. the concentration dependent activity coefficient)
- parameters characterizing electrochemical main and side reactions

\sim ·	·
(₁ Overning	Fallations
	Equations

Finite element model in 1D spatial set		
$o_{Si}\frac{dc}{dc} = -\frac{\partial j_X}{\partial j_X} \qquad \qquad j = -\frac{\partial j_X}{\partial j_X}$	$-\frac{D}{\partial s_i} c \frac{\partial \mu}{\partial \mu}$	Diffusion
$\mu = \mu(c, \sigma) \qquad J$	$RT^{PD_{1}}\partial x$	Chemica
Boundary conditions in galvanostatic tests		
$j_X(H) = \frac{I_R + I_S}{F}$	$j_X(0) = 0$	Cell volta compute
Boundary conditions in potentiastatic tests		
$j_X(H) = \frac{I\left(V - U_0(c,\sigma)\right)}{F}$	$j_X(0) = 0$	Current compute

Thermodynamics of a lithium-ion half cell

Diffusion of Li through the Si electrode is driven by the gradient of the chemical potential $\mu = \mu^{\theta} + RT \ln \left(\frac{c\gamma}{c_{max} - c}\right) - \frac{\sigma^2}{\rho_{Si}}\frac{\partial}{\partial c}\left(\frac{1}{M}\right) - \frac{2\beta\sigma}{3(1 + \beta c)\rho_{Si}}$

It accounts for higher order interactions in non infinite dilute solutions (through the activity coefficient γ) and for the mechanical contribution

As proposed in literature [Verbrugge et al. 1996], we assume the excess of free energy expressed as a series expansion in c/cmax. The open circuit potential can be written as

$$U_{0} = \underbrace{U_{0}^{\theta} - \frac{RT}{F} \ln \left(\frac{c\gamma}{c_{max} - c}\right)}_{\text{ideal solution thermodynamics}} - \underbrace{\sum_{n=2}^{N} \Omega_{n} n \left(\frac{c}{c_{max}}\right)^{n-1}}_{\text{Li-Li interactions}} + \underbrace{\frac{\sigma^{2}}{F\rho_{Si}} \frac{\partial}{\partial c} \left(\frac{1}{M}\right)}_{\text{Li-Li interactions}}$$

Series expansion coefficients Ω_n are calibrated respect the to potential-v-capacity curves available in literature from experiments and DFT calculations [Baggetto et al., 2008], [Chevrier & Dahn, 2009]



The chemical effect on U_0 is represented by the red curve on the left. The hysteresis (orange arrows) is obtained through the stress-potential coupling.

The magnitude of the **stress-potential coupling** in lithiated silicon is estimated to be 62mV/GPa in thin-film geometry [Sethruramna et al., 2010]

Electrochemical reactions

The total current density through the external circuit is divided into two contributions $I = I_R + I_S$ The current supplied to the desired Faradaic reaction is calculated as follows

$$I_R = i_0 \left[\exp\left(\frac{\alpha F\eta}{RT}\right) - \exp\left(-\frac{(1-\alpha)F\eta}{RT}\right) \right] \quad i_0 = F \left[k_c \rho_{Li+} \left(1 - \frac{c}{c_{max}}\right) \right]$$

For the electrolyte-reduction reaction a Tafel kinetics is assumed (Standard SEI models predict that the SEI thickness and total capacity loss vary with time as $t^{1/2}$ and give a good fit to measurements over a long time period [Pinson & Bazant, 2013] but do not fit our experimental data for a small number of cycles)

$$I_S = -i_{0,S} \left(1 - \frac{Q_l}{Q_S} \right) \exp\left[-\frac{\alpha_S F}{RT} \left(V - U_{0,S} \right) \right]; \qquad \qquad Q_l = -\int_0^t I_S dt;$$

The total charge lost Q_S is assumed to be $0.05 C \cdot cm^{-2}$ [Nadimpalli et al. 2012].

Main Reference

Mechanical and Electrochemical response of silicon thin film electrodes combining modeling and in situ measurements.

Giovanna Bucci in collaboration with Siva Nadimpalli, Vijay Sethuraman, Allan Bower and Pradeep Guduru School of Engineering - Brown University - Providence, RI

equation l potential

age and stress

density and stress

 $2\beta\sigma$ $3F(1+\beta c)\rho_{Si}$

 $\sqrt{1-\alpha}$ $\Big]^{\alpha} \left(k_a \frac{c}{c_{max}} \right)$

 $U_{0,S} = 0.8V$

$$\frac{1}{3}\log(1+\beta c) - 2\log(\lambda^p) + \epsilon_{xx}^e = \log\left(1+\frac{1}{3}\log(1+\beta c) + \log(\lambda^p) + \epsilon_{yy}^e\right) = \frac{1}{3}\log(1+\beta c) + \log(\lambda^p) + \epsilon_{yy}^e = \frac{1}{3}\log(1+\beta c) + \log(\lambda^p) + \epsilon_{yy}^e = \frac{1}{3}\log(1+\beta c) + \log(\lambda^p) + + \log(\lambda$$

Assuming a plane stress condition, the Cauchy stress concentration dependent biaxial modulus M(c)

$$\sigma = M(c)\epsilon_{yy}^{e}$$
$$M(c) = M_0 + M_1 \log (1 + c/c_0)$$

stretch rate to stress

$$\epsilon_{yy}^{\dot{p}} = \epsilon_{zz}^{\dot{p}} = \frac{\dot{\lambda}^p}{\lambda^p} = \frac{\dot{\epsilon_0}}{2} \left(\frac{|\sigma|}{\sigma_0} - 1\right)^m \frac{\sigma}{|\sigma|}$$
$$\epsilon_{\dot{p}}^{\dot{p}} = \epsilon_{zz}^{\dot{p}} = 0$$

exponent





- account.
- ► Reaction rate constants extracted form PITT experiment fit the cell voltage data

Li transport and reaction kinetics via PITT experiments

Motivation

- electrode materials.
- several orders of magnitude.

Experiment description

current density in the anode were measured.

Our contribution

- the PITT experiment to the experimental data.
- nonlinearities arising from the Li insertion kinetics.

PITT experiment results



a-Si film of 104nm thickness. Each potentiostatic step was carried out until the current decayed to less than $0.25\mu/cm^2$

- Conclusions
- al., 2013].
- systems vary by several orders of magnitude.



Model of phase boundary propagation in lithiated c-Si and Sn anodes in thin film and spherical particle configurations.

The 1D formulation, developed for the thin film anode case, is being extended to 3D composite configurations with the aim of simulating the interaction between active material, binder and electrolyte.

Acknowledgment Funding from the US Department of Energy EPSCOR Implementation Grant DE-SC0007074 is gratefully acknowledged



► Power density of Li-ion cells is strictly related to the diffusion coefficient for Li transport through

► The range of values available in literature (from experiments and atomistic scale calculations) span

► In the potentiostatic intermittent titration technique experiment, the electrode was subjected to incremental step changes in potential, and the subsequent transient evolution of stress and electric

• Lithium diffusivity and reaction rate constants was determined by fitting full numerical simulations of

► Our approach respect to the classical model [Weppner et al, 1977] accounts rigorously for departures from the ideal diffusion model resulting from stress and free energy of mixing. It also accounts for

• Experimentally measured transients in the PITT test were best fit with a **diffusion coefficient** $10^{-15}cm^2s^{-1}$, which is comparable to, but on the low end of the range $10^{-16} - 10^{-10}cm^2s^{-1}$ measured in previous experiments [Ding et al., 2009] [Ruffo et al., 2009] [Xiao et al., 2012] [Hüger et

► The experiments were also used to estimate the variation of exchange-current density in the Li insertion reaction with concentration. It was found to be $i_0 \sim O(10 \, A \, cm^- 2)$, comparable to the one obtained in [Chandrasekaran et al., 2010], while the values reported in literature for Li-Si battery



